

Vishay Siliconix

RoHS

N-Channel 40 V (D-S) MOSFET

PRODUCT SUMMARY						
V _{DS} (V)	R _{DS(on)} (Ω) MAX.	I _D (A) ^d	Q _g (TYP.)			
40	0.0033 at V_{GS} = 10 V	90	87			
	0.0041 at V _{GS} = 4.5 V	90	07			

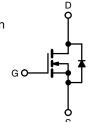


FEATURES

- TrenchFET[®] Power MOSFET
- 100 % R_g and UIS tested
- Material categorization: For definitions of
 COMPLIANT
 compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- Power supply
 - Secondary synchronous rectification
- DC/DC converter
- Power tools



N-Channel MOSFET

Ordering	Information:
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SUM90N04-3m3P-E3	(Lead	(Pb)-free)	
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ABSOLUTE MAXIMUM RATINGS ($T_C = 25 \text{ °C}$, unless otherwise noted)					
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-Source Voltage		V _{DS}	40	V	
Gate-Source Voltage		V _{GS}	V _{GS} ± 20		
Continuous Drain Current (T, = 150 °C)	T _C = 25 °C		90 d		
Continuous Drain Current $(1) = 150^{\circ}$ C)	T _C = 70 °C	- I _D	90 ^d	А	
Pulsed Drain Current (t = 300 μs)		I _{DM}	160	A	
Avalanche Current		I _{AS}	60		
Single Avalanche Energy ^a	L = 0.1 mH	E _{AS}	180	mJ	
Maximum Dawar Dissinction #	T _C = 25 °C	Р	125 ^b	W	
Maximum Power Dissipation ^a	T _A = 25 °C ^c	P _D	3.1	vv	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to 150	°C	

THERMAL RESISTANCE RATINGS					
PARAMETER	SYMBOL	LIMIT	UNIT		
Junction-to-Ambient (PCB Mount) ^c	R _{thJA}	40	- °C/W		
Junction-to-Case (Drain)	R _{thJC}	1			

Notes

- a. Duty cycle \leq 1 %.
- b. See SOA curve for voltage derating.
- c. When mounted on 1" square PCB (FR-4 material).
- d. Package limited.

S13-2462-Rev. B, 02-Dec-13

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SPECIFICATIONS ($T_J = 25 \circ C$	C, unless oth	nerwise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT	
Static							
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS}=0~V,~I_D=250~\mu A$	40	-	-	V	
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = 250 \ \mu A$	1	-	2.5	v	
Gate-Body Leakage	I _{GSS}	$V_{DS}=0~V,~V_{GS}=\pm~20~V$	-	-	± 250	nA	
		V_{DS} = 40 V, V_{GS} = 0 V	-	-	1		
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} = 40 V, V_{GS} = 0 V, T_J = 125 $^\circ C$	-	-	50	μA	
		$V_{DS} = 40 \text{ V}, V_{GS} = 0 \text{ V}, T_J = 150 ^\circ\text{C}$	-	-	250		
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \geq 10 \ V, \ V_{GS} = 10 \ V$	50	-	-	А	
	_	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 22 \text{ A}$	-	0.0027	0.0033	Ω	
Drain-Source On-State Resistance ^a	R _{DS(on)}	V_{GS} = 4.5 V, I_D = 20 A	-	0.0034	0.0041		
Forward Transconductance ^a	9 _{fs}	$V_{DS} = 15 \text{ V}, \text{ I}_{D} = 20 \text{ A}$	-	169	-	S	
Dynamic ^b			1				
Input Capacitance	C _{iss}		-	5286	-	pF	
Output Capacitance	C _{oss}	V_{GS} = 0 V, V_{DS} = 20 V, f = 1 MHz	-	705	-		
Reverse Transfer Capacitance	C _{rss}		-	283	-		
Total Gate Charge ^c	Qg		-	87	131		
Gate-Source Charge ^c	Q _{gs}	V_{DS} = 20 V, V_{GS} = 10 V, I_{D} = 20 A	-	15.3	-	nC	
Gate-Drain Charge ^c	Q _{gd}		-	12.2	-		
Gate Resistance	Rg	f = 1 MHz	0.5	2.7	5.4	Ω	
Turn-On Delay Time ^c	t _{d(on)}		-	11	20		
Rise Time ^c	t _r	V_{DD} = 20 V, R_L = 2 Ω	-	7	14		
Turn-Off Delay Time ^c	t _{d(off)}	$I_D \cong 10$ Å, $V_{GEN} = 10$ V, $R_g = 1$ Ω	-	45	68	ns	
Fall Time ^c	t _f		-	7	14		
Drain-Source Body Diode Ratings a	nd Characteri	stics (T _C = 25 °C) ^b					
Continuous Current	I _S		-	-	90	А	
Pulsed Current	I _{SM}		-	-	160		
Forward Voltage ^a	V _{SD}	$I_{F} = 10 \text{ A}, V_{GS} = 0 \text{ V}$	-	0.72	1.2	V	
Reverse Recovery Time	t _{rr}		-	42	63	ns	
Peak Reverse Recovery Current	I _{RM(REC)}	I _F = 10 A, dl/dt = 100 A/μs	-	2.5	3.8	А	
Reverse Recovery Charge	Q _{rr}		-	52	78	nC	

Notes

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

c. Independent of operating temperature.

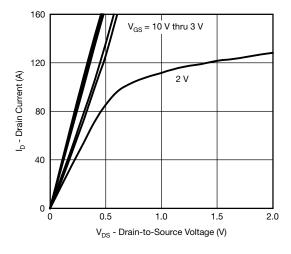
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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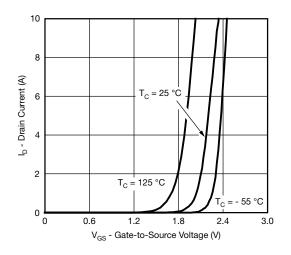


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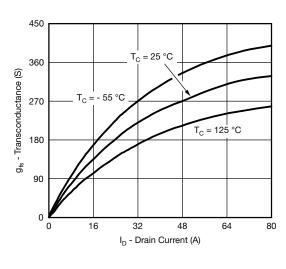
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



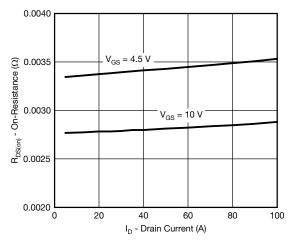
Output Characteristics



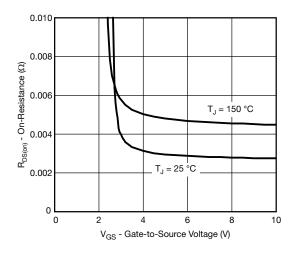




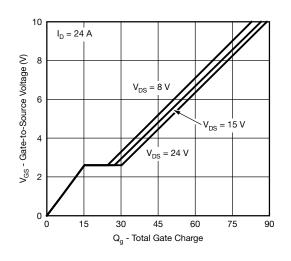
Transconductance



On-Resistance vs. Drain Current







Gate Charge

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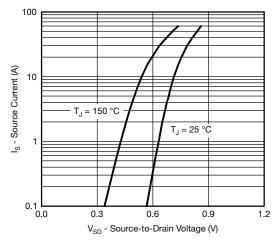
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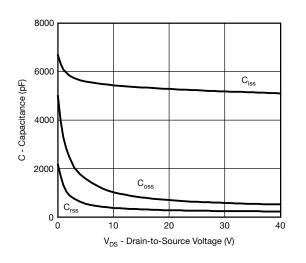
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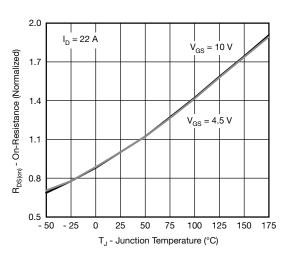
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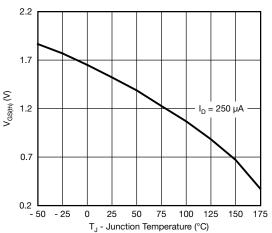
Source-Drain Diode Forward Voltage



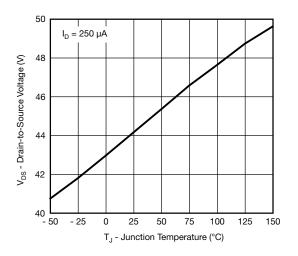


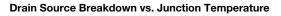


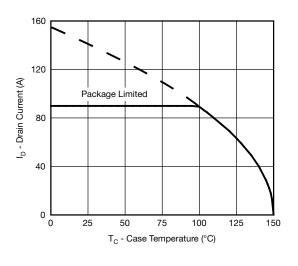
On-Resistance vs. Junction Temperature



Threshold Voltage







Current Derating

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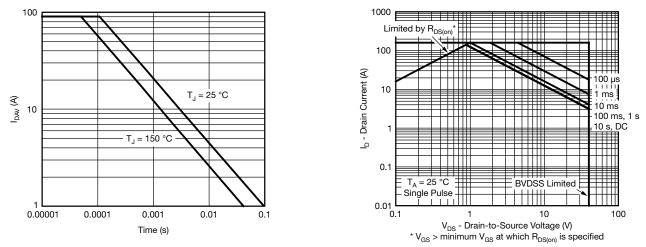
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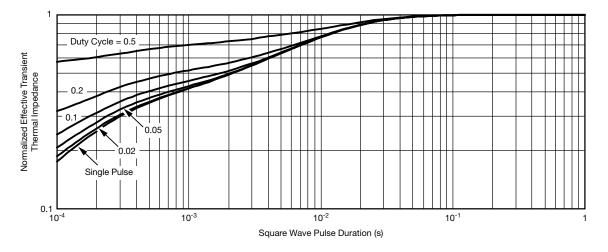
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TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Single Pulse Avalanche Current Capability vs. Time

Safe Operating Area



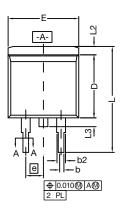
Normalized Thermal Transient Impedance, Junction-to-Case

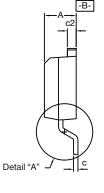
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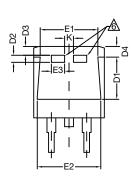


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TO-263 (D²PAK): 3-LEAD









DETAIL A (ROTATED 90°)



		INC	HES	MILLIN	IETERS
DIM.		MIN.	MAX.	MIN.	MAX.
	А	0.160	0.190	4.064	4.826
	b	0.020	0.039	0.508	0.990
	b1	0.020	0.035	0.508	0.889
	b2	0.045	0.055	1.143	1.397
с*	Thin lead	0.013	0.018	0.330	0.457
С	Thick lead	0.023	0.028	0.584	0.711
c1	Thin lead	0.013	0.017	0.330	0.431
CI	Thick lead	0.023	0.027	0.584	0.685
	c2	0.045	0.055	1.143	1.397
	D	0.340	0.380	8.636	9.652
	D1	0.220	0.240	5.588	6.096
	D2	0.038	0.042	0.965	1.067
	D3	0.045	0.055	1.143	1.397
	D4	0.044	0.052	1.118	1.321
	E	0.380	0.410	9.652	10.414
	E1	0.245	-	6.223	-
	E2	0.355	0.375	9.017	9.525
	E3	0.072	0.078	1.829	1.981
	е	0.100	BSC	2.54 BSC	
	К	0.045	0.055	1.143	1.397
	L	0.575	0.625	14.605	15.875
	L1	0.090	0.110	2.286	2.794
L2		0.040	0.055	1.016	1.397
	L3	0.050	0.070	1.270	1.778
	L4	0.010 BSC 0.254 BS		BSC	
	М	-	0.002	-	0.050
ECN: T13-0707-Rev. K, 30-Sep-13 DWG: 5843					

Notes

- 1. Plane B includes maximum features of heat sink tab and plastic. 2. No more than 25 $\,\%\,$ of L1 can fall above seating plane by
- max. 8 mils.3. Pin-to-pin coplanarity max. 4 mils.
- 4. *: Thin lead is for SUB, SYB.
 - Thick lead is for SUM, SYM, SQM.
- 5. Use inches as the primary measurement.

This feature is for thick lead.

Revison: 30-Sep-13



RECOMMENDED MINIMUM PADS FOR D²PAK: 3-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)

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